Quotation should be addressed to the **Registrar**, **HBTU**, **Kanpur**, **Uttar Pradesh-208002**. The envelope should be super scribed with **Quotation for TEQIP-III Package Name** – "…"(**As Applicable**). For any query contact to Shri Jitendra Dwivedi (9721456026). **Quotation are invited for procurement of the item as per the details given below-**

Sr. No.	Package Name	Item Name	Specifications	Quantity	Last Date & Time of Submission of Quotation	Quotation Opening Date & Time
1	EE 1	The three phase power quality analyzer portable in nature and supplied with 4 Flexible clamp on TEQIP-III/UP/hbti/3	Measurement: The analyzer should measure Three phase and phase wise voltage, current, power, power factor, Cos Phi, Energy and demand Dips, Swells, interruptions, crest factor and unbalance Transient detection upto 5μS, 6kV 200kHz on all phases simultaneously Inrush current Flicker Phaser diagram and waveforms Frequency Harmonics for voltage, current and power upto 50 th order, Interharmonics Upto seven power quality parameter in one screen according to EN 50160 Min, Max and Avg value for all RMS measurements. Power loss due to unbalance and Harmonics Inverter Efficiency Energy loss calculator Other feature Graphical screen with display of measurement, waveform, trends and harmonic spectrum	1	05/02/2019 16:00 Hrs	06/02/2019 13:30 Hrs

			 Memory to store atleast two RMS values at user defined interval and wave form during sag/swell and transient Min. of 20screenshots to be stored in the memory The instrument should comply to class A standard as per IEC 61000-4-30. 			
2	EE 2	Single-phase Power Quality Analyzer TEQIP-III/UP/hbti/4	"Measurement: True RMS voltage, current, power, power factor, Cos Phi, VA and Var Dips, Swells, interruptions, K Factor Transient detection upto 40µS or more Inrush current Frequency Harmonics for voltage, current and power upto 50th order and THD Resistance, diode voltage, continuity, and capacitance Other feature Graphical screen with display of measurement, waveform, trends and harmonic spectrum Rechargeable battery with at least 6 hours of uninterrupted operation on Battery Memory to store atleast two RMS values at user defined interval and waveform during sag/swell and transient Minimum of 20 screen shots to be stored in the memory	1	05/02/2019 16:00 Hrs	06/02/2019 13:30 Hrs
3	EE 3	Multipurpose Three Phase Inverter Stack with Chopper TEQIP-III/UP/hbti/5	"(Three Phase diode rectifier + Three phase IGBT based inverter + chopper) Can work as the following: Single Phase Inverter, Three Phase Diode Bridge Rectifier IGBT based Buck Converter IGBT based Boost Converter Three Phase IGBT based inverter IGBT based Chopper Brief Specs: I/P AC Voltage:- 415 Volt DC link Voltage:- 415 Volt O/P AC Voltage:- 415 Volt AC Current:- 25 Amp Switching Frequency:- 2 kHz	1	05/02/2019 16:00 Hrs	06/02/2019 13:30 Hrs

			Fundamental Frequency:- 50 Hz			
			Type of Cooling:- Forced Air			
			Ambient Temp:- 45 Deg			
			Duty Class:- Class I"			
4	EE 4	Three Phase IGBT Stack	"I/P AC Voltage :- 3-PH 480 V	1	05/02/2019	06/02/2019
		with chopper	O/P AC Voltage :- 3-PH 440 V			
		TEQIP-III/UP/hbti/6	I/P DC Link Voltage :- 600 V		16:00 Hrs	13:30 Hrs
			O/P AC Current :- 30 A			
			Switching frequency: - 20 kHz			
			Switching frequency for Brake Chopper :- 5 kHz			
			Fundamental O/P frequency :- 50 Hz			
			Type of cooling :- Forced air			
			Ambient Temp:- 45 Deg			
			Duty Class:- Class I"			
5	EE 5	3 - Level Diode Natural	"Maximum I/P DC Voltage :- 600 V	12	05/02/2019	06/02/2019
		Clamped 3-phase IGBT	O/P AC Voltage :- 3-PH 400 V			
		based	O/P AC Current :- 14 A		16:00 Hrs	13:30 Hrs
			Switching Frequency: - 20 kHz			
		TEQIP-III/UP/hbti/7	Ambient Temperature :- 45 deg			
			Fundamental O/P Frequency :- 50 Hz			
			Type of cooling :- Forced Air			
			Duty Class :- Class I"			
6	EE 6	Five Level Inverter Stack	"DC link Voltage:- 600 Volt	1	05/02/2019	06/02/2019
			O/P AC Voltage:- 415 Volt			
		TEQIP-III/UP/hbti/8	O/P AC Current:- 14 Amp		16:00 Hrs	13:30 Hrs
			Switching Frequency:- 20 kHz			
			Fundamental Frequency:- 50 Hz			
			Type of Cooling:- Forced Air"			
7	EE 7	Nine Level Cascaded 3	"Each H Bridge Specifications	1	05/02/2019	06/02/2019
		Phase Inverter Stack	DC link Voltage:- 200 Volt			
			O/P AC Current:- 14 Amp		16:00 Hrs	13:30 Hrs
		TEQIP-III/UP/hbti/9	Switching Frequency:- 20 kHz			
			Fundamental Frequency:- 50 Hz			
			Type of Cooling:- Forced Air			

			Ambient Temp:- 45 Deg			
			Duty Class:- Class I			
			Total Stack consists of 3 legs . Each leg consists of 4 HBridges			
			(16 IGBTs), Heat sink, 8 Drivers, DC Link capacitors, Fan,			
			Busbar and Thermal trip etc.			
			H-Bridge is isolated to each other. With all terminals brought			
			out."			
8	EE 8	Eleven Level Cascaded 3	"Each H Bridge Specifications	1	05/02/2019	06/02/2019
		phase Inverter Stack	DC link Voltage:- 200 Volt			
		Paris and an annual	O/P AC Current:- 14 Amp		16:00 Hrs	13:30 Hrs
		TEQIP-III/UP/hbti/10	Switching Frequency:- 20 kHz			
			Fundamental Frequency:- 50 Hz			
			Type of Cooling:- Forced Air			
			Ambient Temp:- 45 Deg			
			Duty Class:- Class I			
			Total Stack consists of 3 legs . Each leg consists of 5 HBridges			
			(20 IGBTs), Heat sink, 10 Drivers, DC Link capacitors, Fan,			
			Busbar and Thermal trip etc.			
			H-Bridge is isolated to each other. With all terminals brought			
			out."			
9	EE 9	IGBT MODULE	This module consists of IGBT mounted on heat sink with gate	24	05/02/2019	06/02/2019
			driver. The gating signals are given as an input from an			
		TEQIP-III/UP/hbti/11	appropriate control module. Built in power supplies for the gate		16:00 Hrs	13:30 Hrs
			driver circuitry and the power circuit ±15V @ 1A and 24V @			
			2A, The power suppliers are obtained through an isolation step			
			down transformer after rectification and filtering Gating signals			
			are isolated using opto isolators. Gate drive IC is used for			
			driving the gate, Over current protection is provided through the			
			gate drive IC All terminals of the devices and 24V power supply			
			terminals are brought out to banana sockets mounted at the front			
			panel. The IGBT is rated at 600V, 19A or more, Snubber circuit			
			is to be provided for device to protect against high dv/dt, A hall			
			effect current transducer can be provided for sensing the load			
			current for control purposes as well as to provide protection.			

FORMAT FOR QUOTATION SUBMISSION

(In letterhead of the supplier with seal)

SI.

No.

Contact No: _____

				Date:		_
То:						
Description	Qty	Unit	Quoted Unit rate in Rs.	Total Price	Sales ta	ax and
of goods			(Including Ex Factory price, excise duty,	(A)	other taxes payable	
(with full			packing and forwarding, transportation,			
Specification			insurance, other local costs incidental to		In	In
s)			delivery and warranty/ guaranty		%	figures
			commitments)			(B)
		T/	otal Cost			
			otal Cost			
			Gross Total Cost (A	+B): Rs		_
_			ove goods in accordance with the technica	•		
contract price	of Rs		(Amount in figures) (Rupees -		–amount i	n
words) within	the pe	riod spe	cified in the Invitation for Quotations.			
We confirm th	nat the	normal	commercial warranty/ guarantee of ———-	month	s shall appl	У
			also confirm to agree with terms and conc			-
Invitation Lett	er.					
We hereby ce	rtify th	at we h	ave taken steps to ensure that no person ac	ting for us or o	n our beha	lf
will engage in	bribery	/ .				
Signature of S	upplier					
Name:						
Address:						